

UNISONIC TECHNOLOGIES CO., LTD

US3706

Preliminary

CMOS IC

CURRENT MODE PWM POWER SWITCH

DESCRIPTION

The UTC US3706 combines a dedicated current mode PWM controller with a high voltage power MOSFET. Low VDD startup current make the power reliable on startup design and a large value resistor could be used in the startup circuit to minimize the standby power. At no load condition, the IC operates in power-saving mode for lower standby power, decreasing frequency for Higher conversion efficiency at light load condition.

The UTC US3706 offers complete protection coverage with automatic self-recovery feature including Cycle-by-Cycle current limiting (OCP), over load protection (OLP), over temperature protection (OTP), over voltage protection and V_{DD} under voltage lockout (UVLO).

The internal slope compensation improves system stability at high PWM duty cycle output. Leading-edge blanking on current sense input removes the signal glitch, which offering minimal external component count in the design. Excellent EMI performance is achieved with UTC proprietary frequency hopping technique (ZL201020615247.1) together with soft driver control. Audio noise is eliminated due to switch frequency more than 20kHz during operation.

The US3706 has such applications as: battery charger, power adaptor, set-top box power supplies, ink jet printers, open-frame SMPS.

FEATURES

- * UTC proprietary frequency hopping technology for Improved EMI performance.
- * Power-saving mode for high light-load and standby efficiency
- * Soft Start
- * Dynamic peak current limiting for constant output power * Leading edge blanking on source input
- * Built-in synchronized slope compensation
- **ORDERING INFORMATION** Ordering Number Package Packing Lead Free Halogen Free US3706L-TF6-T US3706G-TF6-T TO-220F-6 Tube





- * OLP, OVP and OTP for higher security
- * Fixed switch frequency 65kHz
- * Low start-up current
- * Cycle-by-cycle Current Limiting
- * Under voltage lockout (UVLO)
- * Few external components required

US3706

MARKING



■ PIN CONFIGURATION



PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	DRAIN	HV MOSFET Drain Pin. The Drain pin is connected to the primary lead of the
		transformer.
2	V _{DD}	Supply voltage
3	Source	HV MOSFET Source Pin.
4	RT	Connected through a NTC resistor to ground for over temperature protection.
5	FB	Feedback input pin. The PWM duty cycle is determined by voltage level into this pin and
		the current-sense signal at Pin 3.
6	GND	Ground

BLOCK DIAGRAM





■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT
V _{DD} Voltage		-0.3~30	V
FB Input Voltage		-0.3~7	V
Source Input Voltage		-0.3~7	V
Operating Junction Temperature	TJ	150	°C
Storage Temperature	T _{STG}	-55~150	°C
Lead Temperature (Soldering, 10secs)	TL	260	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, V_{DD}=16V, R_T=100KΩ, unless otherwise noted)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY SECTION							
Start Up Current		I _{STR}	$V_{DD} = V_{DD(ON)} - 0.1V$		2.5	20	μA
IC Operating current		I _{OP}	V _{FB} =3.5V		2.4	3.0	mA
V _{DD} Zener Clamp currer	nt	VCLAMP	I _{VDD} =10mA	26	27.5	29	V
UNDER-VOLTAGE LO	CKOUT SECTION				-		
Start Threshold Voltage	2	V _{DD(ON)}		12	13.5	15	V
Min. Operating Voltage		V _{DD(MIN)}		7	8	9	V
CONTROL SECTION							
VFB Open Loop Voltage	Level	V_{FB} -Open		4.9	5.1	5.3	V
Burst-Mode Out FB Vol	tage	V _{FB(OUT)}	V _{SENSE} =0		1.6		V
Reduce-Frequency end	FB Voltage	V _{FB(END)}	V _{SENSE} =0		2.2		V
Burst-Mode Enter FB Voltage		V _{FB(IN)}	V _{SENSE} =0		1.5		V
Switch Fraguanay	Normal	L	V _{FB} =3.5V	55	60	65	KHz
Switch Frequency	Power-Saving	FSW	Before enter burst mode	17	22	27	KHz
Duty Cycle		D _{MAX}	V_{FB} =3.5V, V_{SENSE} =0	70	77	85	%
Frequency Hopping		F _{J(SW)}		-4		+4	%
Frequency V _{DD} Stability	,	F _{DV}	V _{DD} =12V~20V			5	%
Frequency Temperature	e Stability	F _{DT}	T=-20~100°C			10	%
Feedback Resistor		R _{FB}		17	20	23	KΩ
PROTECTION SECTIO	N .						
V _{CC} Over Voltage Prote	ction Threshold	VOVP	V _{FB} =3.5V	22.5	23	24.5	V
FB PIN Over Load Protection Threshold		VOLP		4.6	4.8	5.0	V
Power Limiting Debound	ce Time	$T_D_P_L$		100	125	150	mS
Soft start time		T _{SS}		1	2	3	mS
CURRENT LIMITING S	ECTION						
Peak Current Flat Three	shold Voltage	V _{CS-F}	V _{FB} =4.2V, Duty≥60%		0.8		V
Peak Current Valley Th	reshold Voltage	V _{CS-V}	V _{FB} =4.2V, Duty=0%		0.7		V
Lead Edge Blanking Tir	ne	T _{LEB}			350		ns
RT SECTION							
Output current of RT pir	า	I _{RT}		90	100	110	uA
Threshold voltage for O	TP	V _{TH_OTP}		0.9	1	1.1	V
Mosfet Section							
MOSFET Drain-Source Breakdown		B\/dee		600			V
Voltage		DVUSS		000			v
Static Drain to Source On Resistance		Rdson			1.5		Ω



OPERATION DESCRIPTION

The UTC **US3706** is a low power off-line SMPS Switcher optimized for off-line flyback converter. It integrates many useful designs into one controller for low-power switch-mode power supplies. The following descriptions highlight some of the features of the **US3706** series.

Startup Current and Start up Control

The start-up current is only 2.5µA. Low start-up current allows a start-up resistor with a high resistance and a low-wattage to supply the start-up power for the controller. For AC/DC adaptor with universal input range design, a 2.5~ $3M\Omega$, 1/8W startup resistor could be used together with a V_{DD} capacitor to provide a fast startup and low power dissipation solution.

Power-Saving Mode Operation

The proprietary Power-Saving Mode function provides linearly decreasing the switching frequency under light-load conditions for higher efficiency. The feedback voltage, which is sampled from the voltage feedback loop, is taken as the reference. Once the feedback voltage dropped below the threshold voltage, the switching frequency starts to decrease. This Power-Saving Mode function dramatically reduces power consumption under light-load conditions. The 22KHz minimum frequency control also eliminates the audio noise at any loading conditions.

At zero load condition, the magnitude of power loss is in proportion to the number of switching events within a fixed period of time. Reducing switching events leads to the reduction on the power loss and thus conserves the energy. The **US3706** enter burst mode at standby condition to minimize the switching loss and reduces the standby power consumption. Power supplies using the **US3706** can easily meet even the strictest regulations regarding standby power consumption.

Switch Frequency Set

The maximum switch frequency is fixed to 60KHz. Switch frequency is modulated by output power P_{OUT} during IC operating. At no load or light load condition, most of the power dissipation in a switching mode power supply is from switching loss on the MOSFET transistor, the core loss of the transformer and the loss on the snubber circuit. The magnitude of power loss is in proportion to the number of switching events within a fixed period of time. So lower switch frequency at lower load, which more and more improve IC's efficiency at light load. At from no load to light load condition, The IC will operate at from Burst mode to Reducing Frequency Mode. The relation curve between f_{SW} and P_{OUT}/P_{OUT} (MAX) as followed Fig.1.



Fig.1 The relation curve between fsw and relative output power POUT/ POUT (MAX)



OPERATION DESCRIPTION (Cont.)

Frequency Hopping For EMI Improvement

The Frequency hopping is implemented in the IC; there are two oscillators built-in the IC. The first oscillator is to set the normal switching frequency; the switching frequency is modulated with a period signal generated by the 2nd oscillator. The relation between the first oscillator and the 2nd oscillator as followed Fig.2. So the tone energy is evenly spread out, the spread spectrum minimizes the conduction band EMI and therefore eases the system design in meeting stringent EMI requirement.





Built-in Slope Compensation

Built-in slope compensation circuit greatly improves the close loop stability at CCM and prevents the sub-harmonic oscillation.

Leading-Edge Blanking

Each time the power MOSFET is switched on, a turn-on spike will inevitably occur at the sense-resistor. To avoid premature termination of the switching pulse, a 400ns leading-edge blanking time is built in. Conventional RC filtering can therefore be omitted. During this blanking period, the current-limit comparator is disabled and it cannot switch off the power MOSFET.

Under Voltage Lockout (UVLO)

The turn-on and turn-off thresholds of the **US3706** are fixed internally at $V_{DD(ON)}/V_{DD(MIN)}$ During start-up, the hold-up capacitor must be charged to $V_{DD(ON)}$ through the start-up resistor, so that the **US3706** will be enabled. The hold-up capacitor will continue to supply V_{DD} until power can be delivered from the auxiliary winding of the main transformer. V_{DD} must not drop below $V_{DD(MIN)}$ during this start-up process. This UVLO hysteresis window ensures that hold-up capacitor will be adequate to supply V_{DD} during start-up.



OPERATION DESCRIPTION (Cont.)

Protection Controls

The IC takes on more protection functions such as OVP, OLP and OTP etc. In case of those failure occurs for continual blanking time, the power MOSFET is shut down. Power MOSFET is reset after failure is eliminated.

Ο٧Ρ

The OVP will shut down the switching of the power MOSFET whenever $V_{DD} > V_{OVP}$. The OVP event as followed Fig.3.



OLP

OLP will shut down driver when V_{FB}> V_{OLP} for continual a blanking time. The OLP event as followed Fig.4.

ОТР

OTP will shut down driver when the NTC resistor temperature $T_{J}\text{>}T_{(THR)}.$



TYPICAL APPLICATION CIRCUIT



R	o	м
-	S	

Reference	Component	Reference	Component
BD1	2A_600V	R6, R2	Resistor, chip,1.5M, 1/4W,±5%, SMD1206
C2	Capacitor, aluminum electrolytic,33uF/400V, 105°C,±20%	R7, R8	Resistor, chip,180K, 1/4W,±5%, SMD1206
C3	Capacitor, ceramic, 1000pF/1KV, NPO, SMD1206	R13	Resistor, chip,4.7-, 1/8W,±5%, SMD0805
C6	Capacitor, ceramic, 1nF/50V, X7R, SMD0805	R18	Resistor, chip,1K, 1/8W,±5%, SMD0805
C10	Capacitor, aluminum electrolytic,10uF/50V; 105℃,±20%	R20, R21	Resistor, chip, 1.8-, 1/4W,±5%, SMD1206
C7, C46	Capacitor, ceramic, 0.1uF/50V, X7R, SMD0805	R40	Resistor, chip, 47-, 1/4W,±5%, SMD1206
C11	Capacitor, ceramic, 68pF/50V, X7R, SMD0805	R41	Resistor, chip,820-, 1/10W,±5%, SMD0603
C43	Capacitor, aluminum electrolytic, 680uF/25V, 105°C,±20%	R42	Resistor, chip,2.2K, 1/10W,±5%, SMD0603
C45	Capacitor, ceramic, 10NF/50V, X7R, SMD0805	R43	Resistor, chip,300-, 1/10W,±1%, SMD0603
CX1	Capacitor, X2, 0.33uF/275VAC, 105°C ,±20%	R45	Resistor, chip,39K, 1/10W,±1%, SMD0603
CY1	Capacitor, Y1, 1000pF/400V, 105°C,±20%	R47	Resistor, chip,10K, 1/10W,±1%, SMD0603
C40	Capacitor, ceramic, 100pF/200V, ±20%, SMD1206	T1	Transformer, RM-8
D1	Diode , fast recovery, 1N4007, 1.0A/1000V	U1	IC, PWM controller, UTC US3706, TO-220F-6
D3	Diode , fast recovery, BAV20WG, SOT-123	U4	IC, TL431 SOT-23
D5	Diode, MGBR20L60CG, 20A/60V,TO-220	U3	IC, Opto-Coupler, LTV-357-T-C, SMD
F1	Fuse, 3.15A / 250V	No Component	C1, C41, C42, C5, R1, R2, R3, R5, R12, R22, R47
LF1, LF2	choke	PCB	32mmX71mmX1.6mm



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